## SN74CBT16214C 12-BIT 1-OF-3 FET MULTIPLEXER/DEMULTIPLEXER 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTI

12B3 🛮 28

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<ul> <li>Member of the Texas Instruction</li> <li>Widebus™ Family</li> </ul>	uments			PACI VIEW)	
<ul> <li>Undershoot Protection for A and B Ports Up To –2 V</li> </ul>	Off-Isolation on	S0 [ 1A [		- 1	]S1 ]S2
<ul> <li>Bidirectional Data Flow, W Propagation Delay</li> </ul>	ith Near-Zero	1B3 [ 2A [	3	54	]1B1 ]1B2
<ul> <li>Low ON-State Resistance Characteristics (r<sub>on</sub> = 3 Ω</li> </ul>	. 0117	2B3 [ 3A [	5	52	]2B1 ]2B2
<ul> <li>Low Input/Output Capacitation</li> <li>Loading and Signal Distor</li> </ul>		3B3 [ GND [			]3B1 ]GND
(C <sub>io(OFF)</sub> = 5.5 pF Typical)  ■ Data and Control Inputs Pr		4A [ 4B3 [			] 3B2 ] 4B1
Undershoot Clamp Diodes		5A [ 5B3 [			] 4B2 ] 5B1
<ul> <li>Low Power Consumption (I<sub>CC</sub> = 3 μA Max)</li> </ul>		6A [ 6B3 [			]5B2 ]6B1
<ul> <li>V<sub>CC</sub> Operating Range From</li> <li>Data I/Os Support 0 to 5-V</li> </ul>		7A [ 7B3 [		b	]6B2 ]7B1
(0.8-V, 1.2-V, 1.5-V, 1.8-V, 2.  Control Inputs Can Be Driv	•	V <sub>CC</sub> [ 8A [	17	- 1	7B2 8B1
5-V/3.3-V CMOS Outputs	•	GND [ 8B3 [	19	38	GND 8B2
Operation		9A [ 9B3 [	21	36	]9B1 ]9B2
<ul> <li>Latch-Up Performance Exc JESD 78, Class II</li> </ul>	ceeds 100 mA Per	10A [ 10B3 [	23	34	] 10B1 ] 10B2
<ul> <li>ESD Performance Tested F</li> <li>2000-V Human-Body Mo</li> </ul>		11A [ 11B3 [	25	32	] 10B2 ] 11B1 ] 11B2
(A114-B, Class II) - 1000-V Charged-Device	Model (C101)	12A			12B1

## description/ordering information

- 1000-V Charged-Device Model (C101)

Applications: PCI Interface, Bus Isolation,

**Supports Both Digital and Analog** 

**Low-Distortion Signal Gating** 

#### ORDERING INFORMATION

TA	PACK	AGE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
		Tube SN74CBT16214CDL		ODT400440		
4000 / 0500	SSOP – DL	Tape and reel	SN74CBT16214CDLR	CBT16214C		
–40°C to 85°C	T0000 B00	Tube SN74CBT16214CDGG		CDT46244C		
	TSSOP – DGG	Tape and reel	SN74CBT16214CDGGR	CBT16214C		

<sup>†</sup>Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus is a trademark of Texas Instruments.



# SN74CBT16214C 12-BIT 1-OF-3 FET MULTIPLEXER/DEMULTIPLEXER 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION

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#### description/ordering information (continued)

The SN74CBT16214C is a high-speed TTL-compatible FET multiplexer/demultiplexer with low ON-state resistance (r<sub>on</sub>), allowing for minimal propagation delay. Active Undershoot-Protection Circuitry on the A and B ports of the SN74CBT16214C provides protection for undershoot up to -2 V by sensing an undershoot event and ensuring that the switch remains in the proper OFF state.

The SN74CBT16214C is a 12-bit 1-of-3 multiplexer/demultiplexer. The select (S0, S1, S2) inputs control the data path of each multiplexer/demultiplexer. When the multiplexer/demultiplexer is enabled, the A port is connected to the B port, allowing bidirectional data flow between ports. When the multiplexer/demultiplexer is disabled, a high-impedance state exists between the A and B ports.

This device is fully specified for partial-power-down applications using Ioff. The Ioff feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

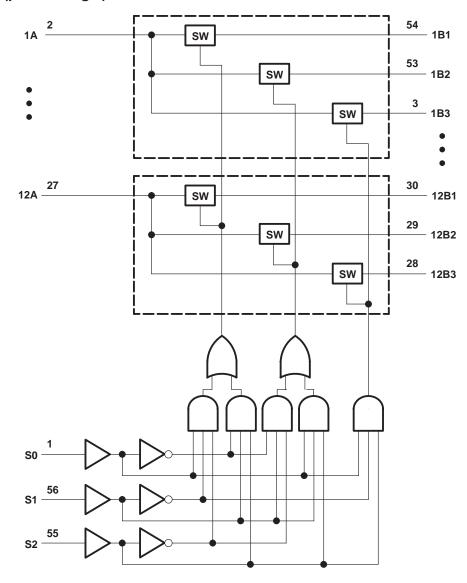
To ensure the high-impedance state during power up or power down, each select input should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

#### **FUNCTION TABLE**

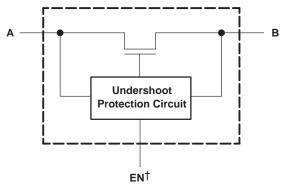
	INPUTS		INPUT/OUTPUT	FUNCTION
S2	S1	S0	Α	FUNCTION
L	L	L	Z	Disconnect
L	L	Н	B1	A port = B1 port
L	Н	L	B2	A port = B2 port
L	Н	Н	Z	Disconnect
Н	L	L	Z	Disconnect
Н	L	Н	В3	A port = B3 port
Н	Н	L	B1	A port = B1 port
Н	Н	Н	B2	A port = B2 port



# logic diagram (positive logic)



## simplified schematic, each FET switch (SW)



<sup>†</sup>EN is the internal enable signal applied to the switch.



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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V <sub>CC</sub>	-0.5 V to 7 V
Control input voltage range, V <sub>IN</sub> (see Notes 1 and 2)	
Switch I/O voltage range, V <sub>I/O</sub> (see Notes 1, 2, and 3)	
Control input clamp current, I <sub>IK</sub> (V <sub>IN</sub> < 0)	
I/O port clamp current, I <sub>I/OK</sub> (V <sub>I/O</sub> < 0)	–50 mA
ON-state switch current, I <sub>I/O</sub> (see Note 4)	
Continuous current through V <sub>CC</sub> or GND terminals	±100 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 5): DGG package	64°C/W
DL package	56°C/W
Storage temperature range, T <sub>eta</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to ground unless otherwise specified.
  - 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
  - 3.  $V_I$  and  $V_O$  are used to denote specific conditions for  $V_{I/O}$ .
  - 4. I<sub>I</sub> and I<sub>O</sub> are used to denote specific conditions for I<sub>I/O</sub>.
  - 5. The package thermal impedance is calculated in accordance with JESD 51-7.

### recommended operating conditions (see Note 6)

		MIN	MAX	UNIT
VCC	Supply voltage	4	5.5	V
VIH	High-level control input voltage	2	5.5	V
VIL	Low-level control input voltage	0	8.0	V
V <sub>I/O</sub>	Data input/output voltage	0	5.5	V
TA	Operating free-air temperature	-40	85	°C

NOTE 6: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PAR	AMETER		TEST CONDITIO	ONS	MIN	TYP <sup>†</sup>	MAX	UNIT
VIK	Control inputs	V <sub>CC</sub> = 4.5 V,	$I_{IN} = -18 \text{ mA}$				-1.8	V
VIKU	Data inputs	V <sub>CC</sub> = 5 V,	$0 \text{ mA} > I_{I} \ge -50 \text{ mA},$ $V_{IN} = V_{CC} \text{ or GND},$	Switch OFF			-2	V
I <sub>IN</sub>	Control inputs	$V_{CC} = 5.5 \text{ V},$	$V_{IN} = V_{CC}$ or GND				±1	μΑ
loz‡		V <sub>CC</sub> = 5.5 V,	$V_O = 0 \text{ to } 5.5 \text{ V},$ $V_I = 0,$	Switch OFF, V <sub>IN</sub> = V <sub>CC</sub> or GND			±10	μΑ
l <sub>off</sub>		$V_{CC} = 0$ ,	$V_0 = 0 \text{ to } 5.5 \text{ V},$	V <sub>I</sub> = 0			10	μΑ
ICC		V <sub>CC</sub> = 5.5 V,	$I_{I/O} = 0,$ $V_{IN} = V_{CC}$ or GND,	Switch ON or OFF			3	μΑ
∆lcc§	Control inputs	$V_{CC} = 5.5 \text{ V},$	One input at 3.4 V,	Other inputs at V <sub>CC</sub> or GND			2.5	mA
C <sub>in</sub>	Control inputs	V <sub>IN</sub> = 3 V or 0				3.5		pF
	A port	V 2.V 2.70	Cuitab OFF	V V m CND		10		pF
C <sub>io(OFF)</sub>	B port	$V_{I/O} = 3 \text{ V or } 0,$	Switch OFF,	$V_{IN} = V_{CC}$ or GND		5.5		pF
C <sub>io(ON)</sub>		$V_{I/O} = 3 \text{ V or } 0,$	Switch ON,	V <sub>IN</sub> = V <sub>CC</sub> or GND		18		pF
		$V_{CC} = 4 \text{ V},$ TYP at $V_{CC} = 4 \text{ V}$	V <sub>I</sub> = 2.4 V,	I <sub>O</sub> = -15 mA		8	12	
r <sub>on</sub> ¶			V. 0	I <sub>O</sub> = 64 mA		3	6	Ω
		V <sub>CC</sub> = 4.5 V	V <sub>I</sub> = 0	I <sub>O</sub> = 30 mA		3	6	
			V <sub>I</sub> = 2.4 V,	$I_{O} = -15 \text{ mA}$		5	10	

 $V_{IN}$  and  $I_{IN}$  refer to control inputs.  $V_I$ ,  $V_O$ ,  $I_I$ , and  $I_O$  refer to data pins.

# switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	TO	V <sub>CC</sub> = 4 V	V <sub>CC</sub> =	= 5 V 5 V	UNIT
	(INPUT)	(OUTPUT)	MIN MAX	MIN		
tpd <sup>#</sup>	A or B	B or A	0.24		0.15	ns
tpd(s)	S	A	6.7	1.5	6.3	ns
t <sub>en</sub>	S	В	7.2	1.5	6.6	ns
<sup>t</sup> dis	S	В	7.5	1.5	7.3	ns

<sup>#</sup>The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).



<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC}$  = 5 V (unless otherwise noted),  $T_A$  = 25°C.

<sup>‡</sup> For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.

<sup>§</sup> This is the increase in supply current for each input that is at the specified voltage level, rather than VCC or GND.

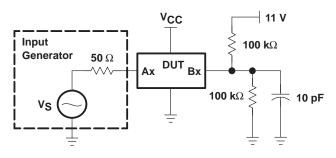
<sup>¶</sup> Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

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### undershoot characteristics (see Figures 1 and 2)

	PARAMETER		TEST CONDI	MIN	TYP†	MAX	UNIT	
ſ	Vоити	$V_{CC} = 5.5 \text{ V},$	Switch OFF,	$V_{IN} = V_{CC}$ or GND	2 '	V <sub>OH</sub> -0.3		V

 $<sup>\</sup>overline{\dagger}$  All typical values are at  $V_{CC} = 5$  V (unless otherwise noted),  $T_A = 25$ °C.





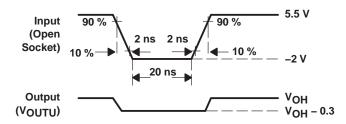
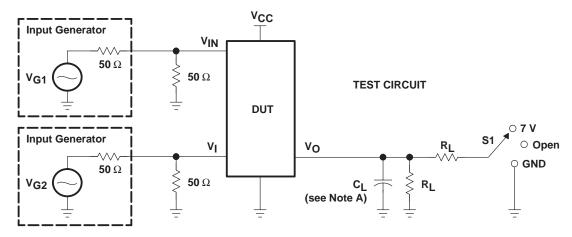


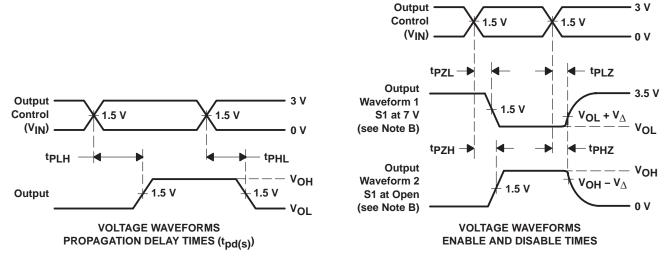
Figure 2. Transient Input Voltage (V<sub>I</sub>) and Output Voltage (V<sub>OUTU</sub>) Waveforms (Switch OFF)

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#### PARAMETER MEASUREMENT INFORMATION



TEST	VCC	S1	RL	VI	CL	${f v}_{\!\Delta}$
<sup>t</sup> pd(s)	$\begin{array}{c} \textbf{5 V} \pm \textbf{0.5 V} \\ \textbf{4 V} \end{array}$	Open Open	<b>500</b> Ω <b>500</b> Ω	V <sub>CC</sub> or GND	50 pF 50 pF	
tPLZ/tPZL	5 V ± 0.5 V 4 V	7 V 7 V	<b>500</b> Ω <b>500</b> Ω	GND GND	50 pF 50 pF	0.3 V 0.3 V
tPHZ/tPZH	5 V ± 0.5 V 4 V	Open Open	<b>500</b> Ω <b>500</b> Ω	v <sub>CC</sub>	50 pF 50 pF	0.3 V 0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{O} = 50 \Omega$ ,  $t_{f} \leq$  2.5 ns,  $t_{f} \leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpl 7 and tpHZ are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd(s). The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Test Circuit and Voltage Waveforms



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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
74CBT16214CDGGRG4	Active	Production	TSSOP (DGG)   56	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT16214C
74CBT16214CDGGRG4.B	Active	Production	TSSOP (DGG)   56	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT16214C
SN74CBT16214CDGGR	Active	Production	TSSOP (DGG)   56	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT16214C
SN74CBT16214CDGGR.B	Active	Production	TSSOP (DGG)   56	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT16214C
SN74CBT16214CDL	Active	Production	SSOP (DL)   56	20   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT16214C
SN74CBT16214CDL.B	Active	Production	SSOP (DL)   56	20   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT16214C
SN74CBT16214CDLR	Active	Production	SSOP (DL)   56	1000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT16214C
SN74CBT16214CDLR.B	Active	Production	SSOP (DL)   56	1000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT16214C

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

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<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

# **PACKAGE OPTION ADDENDUM**

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# **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74CBT16214CDGGRG4	TSSOP	DGG	56	2000	330.0	24.4	8.9	14.7	1.4	12.0	24.0	Q1
SN74CBT16214CDGGR	TSSOP	DGG	56	2000	330.0	24.4	8.9	14.7	1.4	12.0	24.0	Q1
SN74CBT16214CDLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1

# **PACKAGE MATERIALS INFORMATION**

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins SPQ Lengt		Length (mm)	Width (mm)	Height (mm)
74CBT16214CDGGRG4	TSSOP	DGG	56	2000	356.0	356.0	45.0
SN74CBT16214CDGGR	TSSOP	DGG	56	2000	367.0	367.0	45.0
SN74CBT16214CDLR	SSOP	DL	56	1000	356.0	356.0	53.0

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74CBT16214CDL	DL	SSOP	56	20	473.7	14.24	5110	7.87
SN74CBT16214CDL.B	DL	SSOP	56	20	473.7	14.24	5110	7.87

# DL (R-PDSO-G56)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.





SMALL OUTLINE PACKAGE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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